## NSN 5961-01-515-0313

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Inclosure Material:
Plastic
Overall Length:
Between 5.08 millimeters and 5.72 millimeters
Overall Height:
Between 3.48 millimeters and 3.76 millimeters
Overall Width:
Between 3.48 millimeters and 3.76 millimeters
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
43.7 breakdown voltage, dc
Current Rating Per Characteristic:
46.00 milliamperes collector current, dc major
Power Rating Per Characteristic:
500.0 watts forward power dissipation, dc pascal
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0